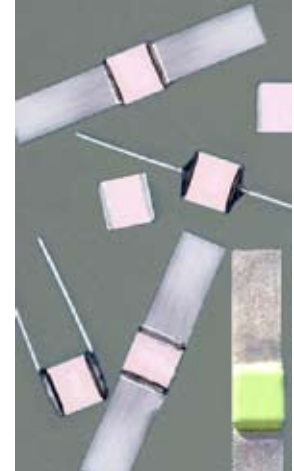


Features

- Capacitance Range: 1pF to 5100pF
- High Q Low ESR/ESL
- High RF Power
- Ultra Stable Performance
- Operating Voltages
 - DC Voltage: 600Vdc to 3600Vdc
 - RF Voltage: 425Vrms to 2500Vrms
- Extended WVDC up to 7200 Vdc
- RF Current Rating 12A rms
- Available with Encapsulation Option

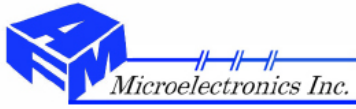
Applications

- MRI Coils
- HF/RF Power Amplifiers
- Plasma Chambers
- Antenna Tuning
- High Power RF Transmitters
- Inductive Heating
- Semiconductor Equipment



AFM Part Number Code

M	P	H	U	1	B	101	J	R	C	M	B	G
Product Series: M: High Frequency	Product Type: H: High Power	Blank: with encapsulated U: Without encapsulated		Termination Code: A: Axial Wire; AN: Non-Mag Axial Wire B: Axial Ribbon BN: Non-Mag Axial Ribbon C: Pd/Ag Term G: Ag Term, Ni/Au Plated M: Microstrip MN: Non-Mag Microstrip N: Non Magnetic Term (Ag Term., Cu/Sn Plated) P: Solder Dipped W Term in 60/40 Sn/Pb Q: Radial Wire QN: Non-Mag Radial Wire T: Ag Term, Ni/100% Sn Plated (Pb Free) W: Ag Term, Ni Barrier, 90/10 Sn/Pb Plated	Case Size: 1: 3838	Tolerance: F: ±1% G: ±2% J: ±5% K: ±10% M: ±20%	Capacitance Code: 1st two digits are significant: Third digit denotes number of zero(s); R=Decimal point 2R0=2.0pF 101=100pF	Voltage: J: 500 Vdc L: 1000 Vdc P: 2500 Vdc R: 3600 Vdc T: 5000 Vdc U: 7200 Vdc	Test Code: C: Commercial Test S: Special (Customer Defined) M: Hi-Rel	Marking: B: Not Marked M: Marked (Cap code and tolerance) S: Special Marking	Packaging: B: Bulk W: Waffle Pack	Encapsulation: Blank: Without Encapsulated G: Glass encapsulated E: Epoxy encapsulated U: Polymer Coating



MPH 1 (MHP1-MHPU1)

High Voltage, High Current, High RF Power Capacitors

Standard Capacitance Values

*STD.: Standard Voltage; EXT.: Extended Voltage

CAP CODE	CAP (pF)	TOL	RATED WVdc		CAP CODE	CAP (pF)	TOL	RATED WVdc		CAP CODE	CAP (pF)	TOL	RATED WVdc	
			STD.*	EXT.*				STD.	EXT.				STD.	EXT.
1R0	1.0	B, C, D	3600	7200	220	22	F, G, J, K, M	3600	7200	471	470	F, G, J, K, M	3600	NA
1R2	1.2				270	27				561	560			
1R5	1.5				330	33				681	680			
1R8	1.8				390	39				821	820			
2R2	2.2				470	47				102	1000			
2R7	2.7				560	56				122	1200			
3R3	3.3				680	68				152	1500			
3R9	3.9				820	82				182	1800			
4R7	4.7				101	100				222	2200			
5R6	5.6				121	120				272	2700			
6R8	6.8	151	150	332	3300	G, J, K, M	500							
8R2	8.2	181	180	472	4700									
100	10	221	220	512	5100									
120	12	F, G, J, K, M			271	270	NA							
150	15				331	330								
180	18				391	390								

* Special capacitance, tolerances and WVDC are available, please consult with AFM.

Specification and Performance

Piezoelectric and Aging Effect:	None
Temperature Range:	-55°C to +125°C
Temperature Coefficient of Capacitance:	+90±30ppm/°C
Quality Factor (Q) :	>10,000 (1pF~1000pF) at 1MHz >10,000 (1100pF~5100pF) at 1KHz
Insulation Resistance (IR, at Rated Voltage):	10 ⁵ MΩ min. at +25°C at rated WVDC 10 ⁴ MΩ min. at +125°C at rated WVDC
Dielectric Withstand Voltage (DWV):	1pF~680pF: 120% of rated WVDC for 5 secs; 820pF~2200pF: 150% of rated WVDC for 5 secs; 2700pF~5100pF: 250% of rated WVDC for 5 secs;
Capacitance Drift:	±0.02% or ±0.02pF, whichever is greater

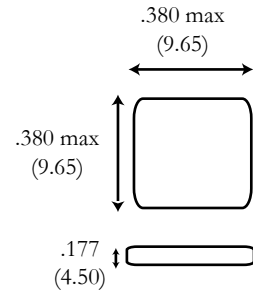
MPH 1 (MHP1-MHPU1)

High Voltage, High Current, High RF Power Capacitors

Chip Dimensions

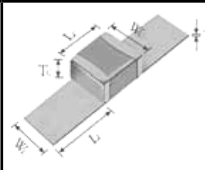
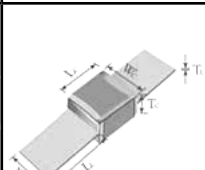
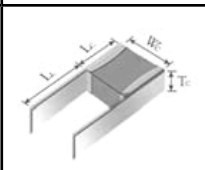
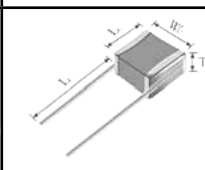
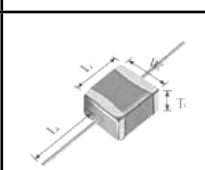
All Dimensions are in Inches (mm)

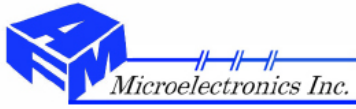
Dimensional Data	Length of Chip / Encapsulated (L) in (mm)	.380 (9.65) / .550(13.97) max after encapsulation
	Width of Chip/ Encapsulated (W) in (mm)	.380 (9.65) / .550(13.97) max after encapsulation
	Thickness of Chip (T) in (mm) (Encapsulated) (max)	.177 (4.50) may increase to .236 (5.99) max. after glass encapsulation



Lead Options

All Dimensions are in Inches (mm)

Term Code	Type	Outlines	Capacitor Dimensions			Lead Dimensions			Lead Material
			Length (Lc)	Width (Wc)	Thickness (Tc)	Length (Lc)	Width (Wc)	Thickness (Tc)	
M/MN	Microstrip/ Non-Magnetic		.380 +.015~--.010 (9.65 +0.38~-0.25)	.038 ±.010 (9.65±0.25)	.177 (4.5) max	.750 (19.05) min	.350 ±.010 (8.89 ±0.25)	.010 ±.005 (0.25 ±0.13)	Solder-plated Copper leaded (Pure Silver Ribbon with Glass Encapsulation)
B/BN	Axial Ribbon/ Non-Magnetic					.787 (20) min	Dia.=.031 ±.004 (0.8 ±0.1)		
R	Radial Ribbon					1.18 (30) min			
Q/QN	Radial Wire/ Non-Magnetic								
A/AN	Axial Wire/ Non-Magnetic								



MPH 1 (MHP1-MHPU1)

High Voltage, High Current, High RF Power Capacitors

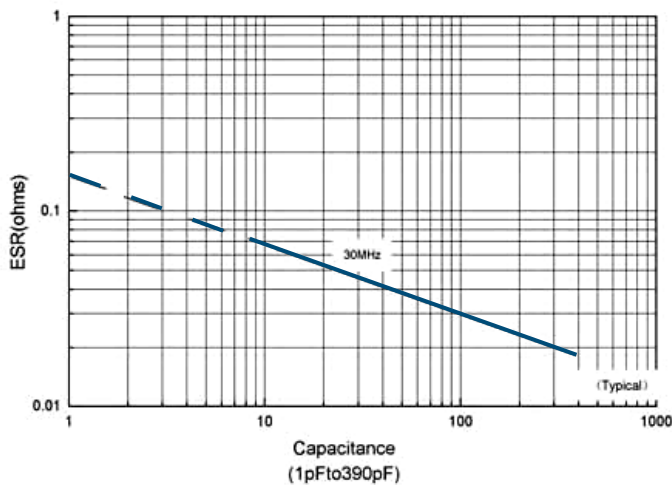
Environmental Tests

MPH1 Series Capacitors are designed and manufactured to meet and exceed the requirements of EIA-198, MIL-PRF-55681 and MIL-PRF-123.

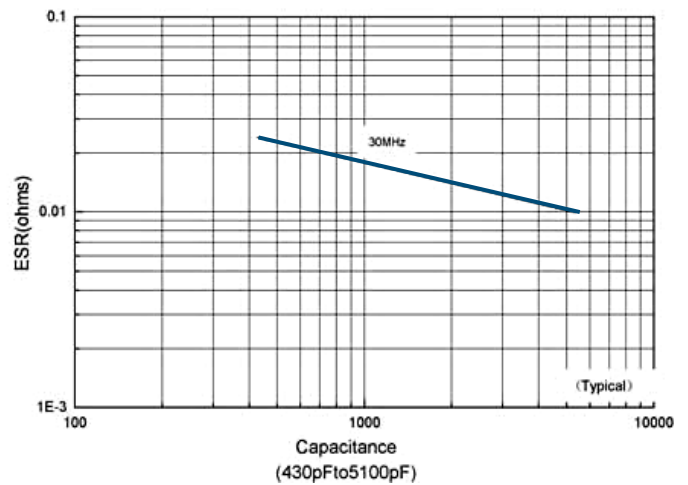
Item	Specifications	Method
Thermal Shock	DWV: the initial value IR: shall be not less than 30% the initial value Capacitance Change: no more than 0.5% or 0.5pF	MIL-STD-202, Method 107, Condition A. At the maximum rated temperature (-55°C and +125°C) stay 30 minutes, the time of removing shall be not more than 3 minutes. Perform the five cycles.
Moisture Resistance		MIL-STD-202, Method 106
Humidity (steady state)	DWV: the initial value IR: the initial value Capacitance Change: no more than 0.3% or 0.3pF	MIL-STD-202, Method 103, Condition A, with 1.5 volts D.C. applied while subjected to an environment of 85°C with 85% relative humidity for 240 hours min.
Life	IR: shall be not less than 30% the initial value Capacitance Change: no more than 0.2%	MIL-STD-202, Method 108, for 2000 hours, at 125°C. Rated voltage $\geq 7200V$: 100% Rated Voltage D.C. applied. 1500V \leq Rated Voltage $< 72000V$: 120% Rated Voltage D.C. applied. Rated voltage $> 1500V$: 150% Rated Voltage D.C. applied.

Performance Curve

ESR vs.Capacitance



ESR vs.Capacitance

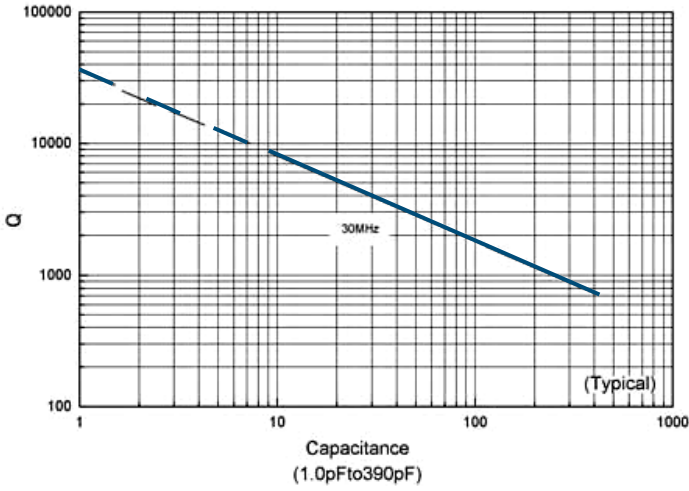




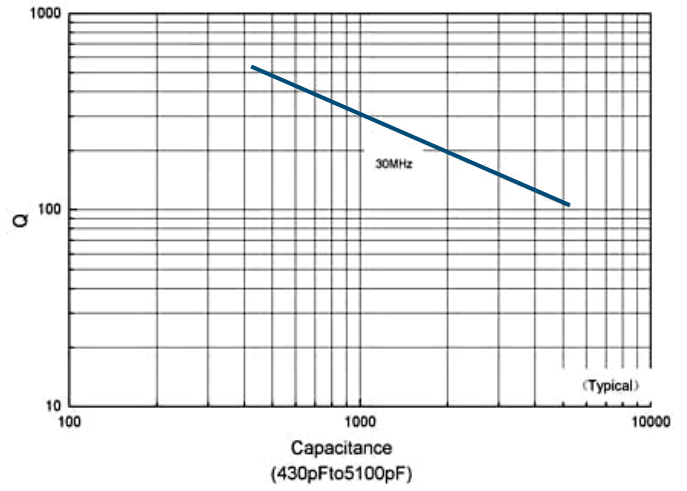
MPH 1 (MHP1-MHPU1)

High Voltage, High Current, High RF Power Capacitors

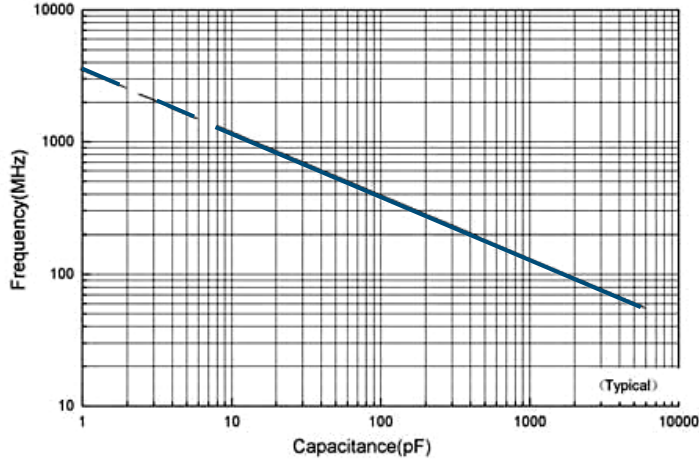
Q vs.Capacitance



Q vs.Capacitance



Resonance vs.Capacitance



Current Rating vs.Capacitance

